

CORRECTION

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Correction: Wafer-scale reliable switching memory based on 2-dimensional layered organic–inorganic halide perovskite

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Correction for 'Wafer-scale reliable switching memory based on 2-dimensional layered organic–inorganic halide perovskite' by Ja-Young Seo, *et al.*, *Nanoscale*, 2017, DOI: 10.1039/c7nr05582j.

The name of one of the co-authors is given incorrectly in the published article. “Huo-Seon Kim” should instead be listed as “Hui-Seon Kim” as provided in the corrected author list above.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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